A nom alous charge transport in triplet superconductor junctions

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C harge transport properties of a di usive norm alm etal/triplet superconductor (D N /T S) junction are studied based on the K eldysh-N am bu quasiclassical G reen's function form alism. C ontrary to the unconventional singlet superconductor junction case, the m id gap A ndreev resonant state (M A R S) at the interface of the T S is shown to enhance the proxim ity e ect in the D N. The total resistance of the D N /T S junction is drastically reduced and is com pletely independent of the resistance of the D N in the extrem e case. Such anom alous transport accompanies a giant zero-bias peak in the conductance spectra and a zero-energy peak of the local density of states in the D N region. These striking features manifest the presence of novel proxim ity e ect peculiar to triplet superconductor junctions.

Physics of superconducting junctions has been one of the exciting elds of solid state physics in this decade [1]. In di usive norm alm etal / conventional singlet s-w ave superconductor (DN/CSS) junctions, it is known that the phase coherence between an incoming electron and an Andreev re ected hole plays an essential role in causing the proxim ity e ect in the DN [2, 3]. It is also known that the total resistance R of DN /CSS junctions does not follow the simple 0 hm 's rule, that is, $R = R_D + R_{R_D} = 0$ where R_D is the resistance in the DN and $R_{R_D} = 0$ is the resistance of the DN/CSS interface. The reduction of R becom es prom inent for low transparent junctions, where $R < R_D + R_{R_D} = 0$ is satisfied [2]. The lower limit of R is given by $R_D + R_0 = 2$ using the Sharvin resistance R_0 , where $R_{R_{D}} = 0 = R_{0} = 2$ is satis ed only for perfect transparent junctions [2]. P revious investigations of the proxin ity e ect, however, are lim ited to DN/CSS junctions. Stim ulated by the successive discovery of unconventional superconductors, we are tem pted to expect novel proxim ity e ect in junctions with unconventional pairing, eg;, pwave, and d-wave, where pair potentials have sign change on the Ferm i surface.

In unconventional superconductor junctions, re ecting the internal phase of the pair potential, charge transport becom es essentially phase sensitive. The most dram atic e ect is the appearance of zero bias conductance peak (ZBCP) [4, 5] in tunneling spectroscopy due to the formation of the mid gap Andreev resonant state (MARS) [6]. The origin of the MARS is due to the anom alous interference e ect of quasiparticles at the interface, where in jected and re ected quasiparticles feel di erent sign of the pair potentials [5]. It is an interesting issue to clarify the role of the MARS on the transport properties of superconducting junctions. Recently, we have developed a theory of proximity e ect, which is available for a di usive norm alm etal / unconventional singlet superconductor (DN/USS) junction, where USS indicates an isotropic singlet pairing like d-wave [7,8]. Unfortunately, how ever, it is revealed that the proximity e ect and the MARS

com pete with each other in DN /USS junctions. A lthough the interface resistance $R_{R_{D}} = 0$ is reduced by the MARS irrespective of the magnitude of the transparency at the interface, the resulting R is always larger than $R_0 = 2 + R_D$. This is because the angular average of m any channels at the DN/USS interface destruct the phase coherence of the MARS and the proximity e ect (see Fig. 1). This destructive angular average is due to the sign change of the pair potentials felt by quasiparticles with injection angle and those with , where the angle is m easured from the direction norm alto the junction interface (see Fig. 1). How ever, in di usive norm alm etal / triplet superconductor (DN/TS) junctions, we can escape from the above destructive average (see Fig. 1). W e can expect enhanced proximity e ect by the MARS. In order to study this signi cantly novel charge transport, we must construct a novel theory for DN/TS junctions beyond preexisting ones[7, 8, 9, 10]. This is in fact very timely since triplet superconductors have been discovered successively very recently [11].

In the present paper, we derive a conductance form ula for DN/TS junctions based on the Keldysh-Nambu (KN) G reen's function form alism [7, 8]. The total zero voltage resistance R in the DN/TS junctions is signi cantly reduced by the enhanced proximity e ect in the presence of the MARS. At the same time, local density of states (LDOS) in the DN region has zero energy peak (ZEP) due to the penetration of the MARS into the DN region from the triplet superconductor (TS) side of the DN/TS interface. It is remarkable that when R_D is su ciently larger than the Sharvin resistance R_{0} , R is given by R = R_0=C , which can become much smaller than the preexisting lower lim it value of R, is; $R_0=2 + R_D$. In the above, C is a constant completely independent of both R_D and R_B , where R_B denotes the interface resistance in the norm al state. W hen all quasiparticles injected at the interface feel the MARS, R is reduced to be $R = R_0 = 2$ irrespective of the magnitude of R_D and R_B. The line shape of the bias voltage V dependent conductance (eV) has a giant ZBCP. These novel features have never been expected either in DN/CSS or DN/USS junctions.

We consider a DN/TS junction with TS term inal and normal reservoir (N) connected by a quasi-onedim ensionaldi usive conductor (DN) having a resistance R_D . The at interface between the DN and the TS has a resistance R_B while the DN/N interface has zero resistance. The positions of the DN/N interface and the DN/TS interface are denoted as x = L and x = 0, respectively as shown in Ref. [8]. We restrict our attention to triplet superconductors with $S_z = 0$ that preserves time reversal symmetry. S_z denotes the z component of the total spin of a Cooper pair. It is by no means easy to formulate a charge transport of DN/TS junctions since the quasiparticle G reen's function has no anquar dependence by the impurity scattering in the DN. However, as shown in our previous paper [7, 8], if we concentrate on the matrix currents [9, 10] via the TS to or from the DN, we can make a boundary condition of the KN Green's function. We assume that the constriction area between the DN and the TS is subdivided into an anisotropic zone in the DN, two ballistic zones in the DN and the TS, and a scattering zone, where both ballistic and di usive regimes can be covered [8]. The sizes of the ballistic zone in the DN and the scattering zone in the current ow direction are much shorter than the coherence length [7, 8, 9]. The scattering zone is m odeled by an insulating delta function barrier with the transparency T () = $4\cos^2 = (4\cos^2 + Z^2)$, where Z is a dimensionless constant and is measured from the interface norm alto the junction [8]. The boundary condition for the KN G reen's function in the DN $[G_N(x)]$ at the DN/TS interface is given by,

$$\frac{L}{R_{D}} \quad G_{N}(\mathbf{x}) \frac{\partial G_{N}(\mathbf{x})}{\partial \mathbf{x}} = \frac{h}{2e^{2}R_{B}}hIi; \quad (1)$$

using m atrix current I [7, 8]. A verage over the angle of injected particles at the interface is de ned by

$$Z_{=2}$$
, $Z_{=2}$
hI()i d cos I() d T()cos (2)
=2 =2

with I () = I. The resistance of the interface R_B is given by $R_B = \langle R_0 \rangle$. A shown in the eq. (2) in our previous paper [7], matrix current I is a function of T (), $G_1 = G_N (x = 0)$, G_{2+} , and G_2 , where $G_{2+} (G_2)$ denotes the outgoing (incoming) G reen's function in the TS. The G reen's functions are xed in the "TS" term inal and in the "N" term inal, and the voltage V is applied to the "N" term inal located at x = L. $G_N (x)$ is determ ined from the U sadel equation with eq. (1). If we denote the retarded part of $G_N (x)$ and $G_2 = as \hat{R}_N (x)$ and \hat{R}_2 [8], the following equations are satis ed, $\hat{R}_N (\underline{C} L) = \hat{C}_2$, $\hat{R}_2 = (f_N + g_N (\underline{C}) with f_2 = () = \frac{2}{2} ()$ and $g = 2^{2}^{2}$ (), using the Pauli matrices. denotes the energy of the quasiparticles measured from the Ferm i energy. + () [()] is the pair potential felt by the outgoing (incoming) quasiparticles (see Fig. 1). A fter som e algebra, we can show that \hat{R}_{N} (x) is given by sin (x) $x^{+} \cos$ (x) z^{-} . The spatial dependence of (x) in the DN is determined by the following equation

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$$D \frac{\theta^{2}}{\theta x^{2}} (x) + 2i \sin[(x)] = 0;$$
 (3)

with di usion constant D in the DN. Taking the retarded part of Eq. (1), we obtain

$$\frac{L}{R_{D}} \frac{\varrho(\mathbf{x})}{\varrho \mathbf{x}} = \frac{h2B_{R}i}{R_{B}}; \qquad (4)$$

$$B_{R} = \frac{(1 \cos 0) 2 \sin 0 T}{(2 T ()) 3 + T () \cos 0 2 + \sin 0 1};$$

with $_{0} = (x = 0)$, $_{2} = g_{+} + g_{-3} = 1 + f_{+} f_{+} + g_{+} g_{-3}$ and $1 = i(f_+ g_- g_+ f_-)$. Here, we focus on = 0, where the left hand side of Eq. (4) is reduced to be $_0=R_D$. We de ne F () as F () = $\lim_{t \to 0} f = \operatorname{sign}(())$ with sign (+()) = 1(1) for +() > 0 < 0. In the following, we de ne the term inology as follows : when () > 0 is satis ed, quasiparticles are in the + () conventional channels (CC), while when + () () < 0 is satis ed, quasiparticles are in the unconventional channels (UC). In UC, quasiparticles feel the MARS while in CC quasiparticles do not feel the MARS.Follow ing the above de nition, F_+ () = F () is satisfied for CC, while for UC, F_+ () = F () is satisfied. From eq. (4), we can show that B_R is zero for CC and $B_R = iF_+$ () for UC, respectively. Then, 0 becomes 7

$$_{0} = iR_{D}C = R_{0}; C = F_{+} () \cos d;$$
 (5)

^R where $_{UC}$ means the integral only from the UC within =2 < < =2. A remarkable feature is that $_0$ becomes a purely in aginary number as shown below. From eq. (3), (x) at = 0 becomes (x) = (x + L)_0=L. Since the LDOS of the quasiparticles in the DN region renormalized by its value in normal state is given by () = Real[cos (x)], (0) is always larger than unity except for x = L. This means that (0) is enhanced due to the enhanced proximity e ect by the MARS and has a ZEP as shown later. In the preexisting theories of DN/CSS and DN/USS junctions, $_0$ at = 0 is always a real number and (x) never exceeds unity.

In order to understand the essential di erence between the DN/TS junctions and the DN/USS junctions intuitively, we consider four simpli ed cases, (a) the DN/CSS junctions with the CC, (b) the DN/CSS junctions with the UC, (c) the DN/TS junctions with the CC, and (d) the $\rm D~N/T~S$ junctions with the UC for all $% \rm C~Imms$. This situation is actually realized by choosing d-wave pair potential with

() =)] (Figs. 1(a) and 1(b)) and ₀cos[2(p-wave pair potential with () = $_0 \cos($) (Figs. 1(c) and 1(d)) as a prototype of USS and TS, respectively. The relations F_+ () = F () and F_+ () = F_- (), are satisfied for the DN/USS and the DN/TS junctions, respectively both for the UC and for the C C. For the D N /U SS junctions with the C C, since F () = F () is satisfied, the contribution to $_{0}$ is not cancelled by angular averaging Fig. 1(a)]. For the DN/USS junctions with the UC and the DN/TS junctions with the CC, since F() = F() is satisfied, the contribution to $_0$ is cancelled by the angular average [Figs. 1 (b) and 1 (c)]. However, for the DN /TS junctions with UC, since F () = F () is satisfied, the contribution to $_0$ is non-zero F iq. 1(d)]. It is remarkable that for the DN/TS junctions the CC do not contribute to the proximity e ect while UC do.

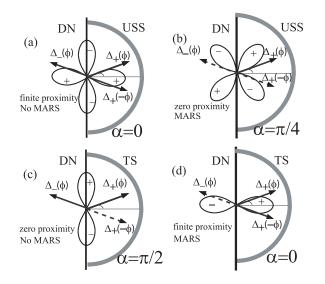


FIG.1: Trajectories in the scattering process for outgoing (incom ing) quasiparticles for the DN/USS and the DN/TS junctions and the corresponding () are schem atically illustrated. As a prototype, we choose = $_0 \cos[2($)] for the DN/USS junctions [(a) and (b)] and =

 $_0 \cos[()]$ for the D N/T S junctions [(c) and (d)], respectively, where $_0$ is the maximum value of the pair potential. The measure of the proximity e ect $_0$ is determined by the integration for all injection angles, i.e., the angular average over the hatched area.

The total zero voltage resistance of the DN/TS junction can be given as

$$R = \frac{R_{D}}{L} \int_{L}^{L_{0}} \frac{dx}{\cos^{2}(x)} + \frac{R_{B}}{hI_{b0}i};$$
 (6)

where I_{b0} is obtained from the Keldysh part of I and is a complex function of g , f , _0, and T (). At = 0, I_{b0} becomes 1 + exp(2 j _0) for UC, while for CC, I_{b0}

$$R = R_{0}f\frac{\tanh_{0i}}{C} + \frac{2}{[1 + \exp(2j_{0i})]C_{+} + \cosh^{2}_{0i}D}g$$
(7)

 $\mathbf{D}_{\mathbf{D}_{\mathbf{D}}}^{\mathbf{D}_{\mathbf{D}}} = \mathbf{i}_{\mathbf{D}} = \mathbf{R}_{\mathbf{D}} \mathbf{C} = \mathbf{R}_{\mathbf{D}}, \mathbf{C}_{+} = \frac{\mathbf{R}_{\mathbf{D}}}{\mathbf{U}_{\mathbf{C}}} \cos d$ and with 2T²() $c_{c} \frac{21}{[2 T()]^2} d$, where c_{c} means the integral D = only from the CC. The resulting R is given by $R_0 = C$ for su ciently large R $_{\rm D}$ =R $_{\rm 0}$ and is independent both of R $_{\rm D}$ and R_B except for the very special case with C = 0. The m agnitude of R can becom e m uch sm aller than the preexisting lower lim it value of R, i:e:, $R_0 = 2 + R_D$. This giant reduction of R is due to the enhanced proximity e ect by the MARS.W hen all quasiparticles feel the MARS independent of , C is given by 2 and R becomes $R = R_0 = 2$ independent of $R_{\,D}\,$ and $R_{\,B}$. This interesting situation is actually realized for a px-wave case, where pair potentials are given by () = $_0 \cos$ [see case Fig. 1(d)]. Above enhanced proximity e ect by the MARS is a completely novel proximity e ect, which has never been expected in any preexisting theories [2, 7, 8, 9, 10].

In order to understand this novel proximity e ect in detail, we focus on the LDOS () in the DN region normalized by its value in the normal state. We choose $p_x - w$ ave pairing as a prototype of the TS.As a reference, we compare the results with those for the DN/USS junction with d_{xy} -wave pair potential, where () is given by () = $_0 \sin(2)$. Although () at the TS side of the DN/TS interface and that at the USS side of the DN/USS interface both have ZEP by the formation of the MARS, () in the DN has a drastic di erence between the two cases. For the p_x -wave case, the LDOS in the DN region has a ZEP. The height of the ZEP

(0) is given by $\cosh [2R_D (x + L) = (LR_0)]$ and the order of its width is E_{Th} . On the other hand, for the d_{xy} wave case, () is always unity independent of R_D due to the absence of the proxim ity e ect. Contrary to the DN/TS junction, the MARS form ed at the USS side of the DN/USS interface can not penetrate into the DN.As seen from () in DN/TS junctions, the signi cant reduction of R originates from the penetration of the MARS into the DN. Although we have actually shown the existence of ZEP of () in the DN for p-wave case as a prototype, ZEP is universally expected for DN/TS junctions with the MARS at the interface independent of the detailed shape of the pair potentials of the TS.On the other hand, the LDOS in the DN region of DN /USS junctions do not have ZEP. Using this clear and qualitative di erence of LDOS in the DN region between the DN/TS and DN/USS junctions, we can identify the triplet sym metry of the pair potentials.

Finally, we focus on the line shape of the tunneling conductance of DN/TS junctions for non zero voltage, which is de ned by (eV) = $R_B = R$ (eV). We choose

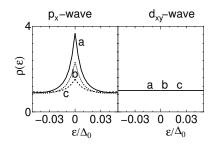


FIG.2: () is plotted for the D N /T S junction with p-wave superconductor (left panel) and the D N /U SS junction with d_{xy} -wave superconductor (right panel) for Z = 1.5, $R_{\rm D}$ = $R_{\rm B}$ = 0.5, and $E_{\rm T\,h}$ = 0.02 $_0$ with various x in the D N .a: x = 0 , b: x = L=4 and c: x = L=2.

 p_x -wave pairing as a prototype. As a reference, we com pare the results with those for the DN /USS junction with d_{xy} -wave pair potential. Although both p_x -wave and d_{xy} -wave cases have sim ilar line shapes of the voltagedependent conductance with the ZBCP as a function of eV for ballistic junctions [12], i.e. $R_D = 0$ case, we can classify these two for R_D € 0 as shown in Fig. 3. We choose the Thouless energy E_{Th} as $E_{Th} = 0.02_{0}$. For the px-wave case, since all injected quasiparticles feel the MARS, (0) = $2R_B = R_0$ is satisfied for any R_D . For $R_{\rm D}~~{\mbox{fe}}~0$, (eV) can be expressed by the sum m ation of the broad ZBCP and the narrow one, where $N = R_0 = R_B$ denotes the angular averaged transparency of the junction. The width of the form er one is proportional to $_{\rm N}$ o and the latter one is the Thouless energy. How ever, with the increase of R $_{\rm D}$ =R $_{\rm B}$, (eV) for jeV \Rightarrow E $_{\rm T h}$ is suppressed, and the ratio of (0) to its background value is largely enhanced. We can call this largely enhanced (0) as giant ZBCP (curve b or c in the left panel of Fig. 3). By contrast, for d_{xy} -wave case, since $(0) = 2R_B = (R_0 + 2R_D)$ is satisfied, (0) is reduced with the increase of $R_{\,\text{D}}$. The width of ZBCP is proportional

to $_{0 \text{ N}}$ and is not changed with the increase of $R_{D} = R_{B}$ due to the absence of the proximity e.ect.

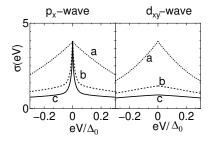


FIG. 3: (eV) is plotted as a function of eV for the DN/TS junctions with p_x -wave superconductor (left panel) and the DN/USS junctions with d_{xy} -wave superconductor (right panel) for Z = 1:5 and E_{Th} = 0:02 $_0.a:R_D = R_B = 0$, b: $R_D = R_B = 0:5$ and c: $R_D = R_B = 1$.

In conclusion, we have presented a theory of charge transport in the DN/TS junctions. The total resistance R can become much smaller than the preexisting lower limit value of R for DN/CSS and DN/USS junctions, i:e:, $R_0 = 2 + R_D$. As the extrem e case where all injected electrons feel the MARS, R is reduced to be $R_0=2$. The signi cant reduction of R is due to the enhanced proxin ity e ect by the MARS and the resulting LDOS in the DN region has a ZEP. At the same time, we can expect giant ZBCP. The above enhanced proximity effect is a novel proximity e ect, which has never been expected in DN/CSS and DN/USS junctions. We have shown in the present paper that these e ects are actually realizable for DN/TS junctions with p-wave pair potential. We believe that these features are easily veriable in experim ents since a m esoscopic interference e ect due to the proximity e ect has recently been observed in high T_C cuprate junctions [13]. Sim ilar experim ents are technologically possible for junctions composed of Sr₂RuO₄,

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where triplet pairing is believed to be realized [11].

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